

Kuang-I Lin

List of Publications by Year in descending order

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9
papers

269
citations

1651377

6
h-index

1637695

9
g-index

9
all docs

9
docs citations

9
times ranked

703
citing authors

#	ARTICLE	IF	CITATIONS
1	Oxidation and Degradation of WS ₂ Monolayers Grown by NaCl-Assisted Chemical Vapor Deposition: Mechanism and Prevention. <i>Nanoscale</i> , 2021, 13, 16629-16640.	2.8	7
2	Embedment of Multiple Transition Metal Impurities into WS ₂ Monolayer for Bandstructure Modulation. <i>Small</i> , 2021, 17, e2007171.	5.2	6
3	Photogating WS ₂ Photodetectors Using Embedded WSe ₂ Charge Puddles. <i>ACS Nano</i> , 2020, 14, 4559-4566.	7.3	87
4	Fast Real-Space Imaging of the Exciton Complexes in WSe ₂ and WS ₂ Monolayers Using Multiphoton Microscopy. <i>Journal of Physical Chemistry C</i> , 2020, 124, 7979-7987.	1.5	4
5	Atom-Dependent Edge-Enhanced Second-Harmonic Generation on MoS ₂ Monolayers. <i>Nano Letters</i> , 2018, 18, 793-797.	4.5	51
6	Synthesis of Large-Area InSe Monolayers by Chemical Vapor Deposition. <i>Small</i> , 2018, 14, e1802351.	5.2	81
7	Photoreflectance study of the near-band-edge transitions of chemical vapor deposition-grown mono- and few-layer MoS ₂ films. <i>Journal of Applied Physics</i> , 2016, 119, .	1.1	13
8	Investigation of valence-band splitting in InN by low-temperature photoreflectance spectroscopy. <i>Japanese Journal of Applied Physics</i> , 2015, 54, 031001.	0.8	4
9	Double-Band Anticrossing in GaAsSbN Induced by Nitrogen and Antimony Incorporation. <i>Applied Physics Express</i> , 2013, 6, 121202.	1.1	16